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	Filing Date		2006-06-17
	First Named Inventor	Tetsuo Fujii	
	Art Unit	2815	
	Examiner Name	Jerome Jackson, Jr.	
	Attorney Docket Number	30794.108-US-WO	

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	4	Stonas et al., "Backside-illuminated photoelectrochemical etching for the fabrication of deeply undercut GaN structures". Applied Physics Letters, Volume 77, No. 16, October 16, 2000, pgs. 2610-2612.	<input type="checkbox"/>
	5	Compound Semiconductor: Connecting the Compound Semiconductor Community, March 2007, Volume 12, Number 2, pgs. Cover page, 1, and 14-16.	<input type="checkbox"/>
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	8	Rattier et al., " Toward Ultrahigh-Efficiency Aluminum Oxide Microcavity Light-Emitting Diodes: Guided Mode Extraction by Photonic Crystals". IEEE Journal on Selected Topics In Quantum Electronics, Vol. 8, No. 2, March/April 2002, pgs. 238-247.	<input type="checkbox"/>

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9	Quality by Design: SemiLEDs. 2009, pgs. 1-4. <a href="http://www.semileds.com/Quality_by_Design_SemiLEDs.htm">http://www.semileds.com/Quality_by_Design_SemiLEDs.htm</a>	<input type="checkbox"/>
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